

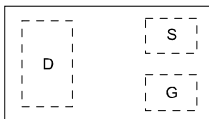
Product Summary

- V_{DS} 60V
- I_D 340mA
- $R_{DS(ON)}$ (at $V_{GS}=10V$) <2.5ohm
- $R_{DS(ON)}$ (at $V_{GS}=4.5V$) <3.0ohm

Application

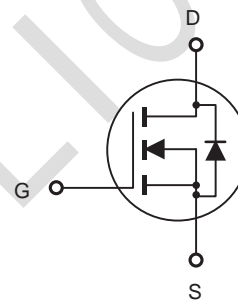
- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

Package and Pin Configuration



DFN1006-3L

Circuit diagram



Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	0.32	A
Pulsed Drain Current	I_{DM}	1	A
Power Dissipation	P_D	0.5	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	258	$^\circ\text{C/W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55~ +150	$^\circ\text{C}$

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	60			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$			1	μA
Gate-Body Leakage Current	I_{GSS1}	$V_{GS}= \pm 20V, V_{DS}=0V$			± 100	nA
	I_{GSS2}	$V_{GS}= \pm 10V, V_{DS}=0V$			± 50	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}= V_{GS}, I_D=250\mu A$	1	1.5	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}= 10V, I_D=300mA$		1.2	2.5	Ω
		$V_{GS}= 4.5V, I_D=200mA$		1.3	3.0	
Diode Forward Voltage	V_{SD}	$I_S=300mA, V_{GS}=0V$			1.2	V
Maximum Body-Diode Continuous Current	I_S				340	mA

Dynamic Parameters

Input Capacitance	C_{iss}	$V_{DS}=30V, V_{GS}=0V, f=1MHz$		16		μF
Output Capacitance	C_{oss}			10		
Reverse Transfer Capacitance	C_{rss}			5.5		

Switching Parameters

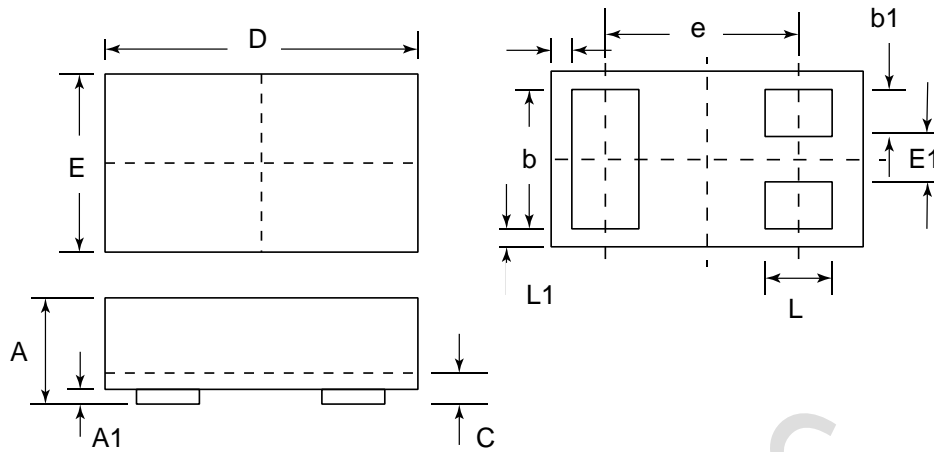
Total Gate Charge	Q_g	$V_{GS}=10V, V_{DS}=30V, I_D=0.3A$		1.7	2.4	nC
Turn-on Delay Time	$t_{D(on)}$	$V_{GS}=10V, V_{DD}=30V, I_D=300mA, R_{GEN}=6\Omega$		5		ns
Turn-off Delay Time	$t_{D(off)}$			17		
Reverse recovery Time	t_{rr}	$V_{GS}=0V, I_S=300mA, V_R=25V, di_S/dt=-100A/\mu s$		30		ns

A. Pulse Test: Pulse Width $\leq 300\mu s$, Duty cycle $\leq 2\%$.

B. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.

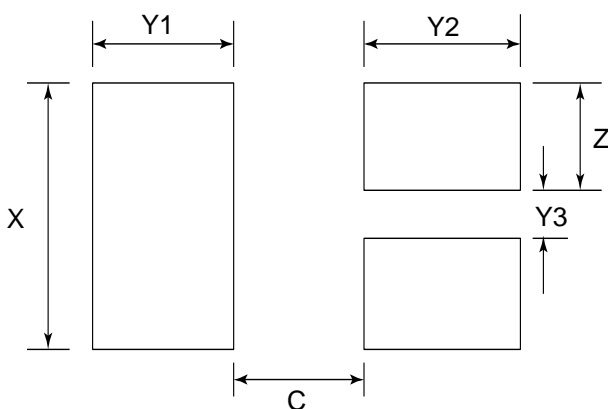
DFN1006 3L Package Outline Drawing

www.sot23.com.tw



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
b1	0.10	0.15	0.20	0.004	0.006	0.008
C	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
E1	0.15	0.20	0.25	0.006	0.008	0.010
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.05 REF			0.0002 REF		

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	0.25	0.010
X	0.65	0.024
Y1	0.50	0.020
Y2	0.50	0.020
Y3	0.25	0.010
Z	0.20	0.008